EFS ID: 2715033  Application Number: 10586849  International Application Number: 3462  Title of Invention: Gallium nitride-based compound semiconductor multilayer structure and production method thereof  First Named Inventor/Applicant Name: Hisayuki Miki Customer Number: 23373  Filer: Abraham Jacob Rosner/Michelle Delozier  Filer Authorized By: Abraham Jacob Rosner  Attorney Docket Number: 079703  Receipt Date: 14-JAN-2008  Filing Date: 20-JUL-2006  Time Stamp: 19:07:40	Electronic Acknowledgement Receipt				
International Application Number:  Confirmation Number:  3462  Title of Invention:  Gallium nitride-based compound semiconductor multilayer structure and production method thereof  First Named Inventor/Applicant Name:  Hisayuki Miki  Customer Number:  23373  Filer:  Abraham Jacob Rosner/Michelle Delozier  Filer Authorized By:  Abraham Jacob Rosner  Attorney Docket Number:  Q79703  Receipt Date:  14-JAN-2008  Filing Date:  20-JUL-2006	EFS ID:	2715033			
Confirmation Number:  3462  Title of Invention:  Gallium nitride-based compound semiconductor multilayer structure and production method thereof  First Named Inventor/Applicant Name: Hisayuki Miki  Customer Number: 23373  Filer: Abraham Jacob Rosner/Michelle Delozier  Filer Authorized By: Abraham Jacob Rosner  Attorney Docket Number: Q79703  Receipt Date: 14-JAN-2008  Filing Date: 20-JUL-2006	Application Number:	10586849			
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	Receipt Date:	14-JAN-2008			
Time Stamp: 19:07:40	Filing Date:	20-JUL-2006			
	Time Stamp:	19:07:40			
Application Type: U.S. National Stage under 35 USC 371	Application Type:	U.S. National Stage under 35 USC 371			
Payment information:	Payment information:				

Submitted with Payment	no

## File Listing:

Document Number	Document Description	File Name	File Size(Bytes) /Message Digest	Multi Part /.zip	Pages (if appl.)
1		Q79703AMD111.pdf	544232	yes	12
'			e85aacc5720dfefc813f6ad167648134e b5186a3		

	Multipart Description/PDF files in .zip description						
	Document De	Start	End				
	Amendment - After No	1	1				
	Claims	2	7				
	Applicant Arguments/Remarks Made in an Amendment		8	12			
Warnings:							
Information	:						
2	Drawings-only black and white line	Q79703REPLACEMENTDW GS.pdf	1343710	no	4		
2	drawings		470ca352d45a4ha952d766b1bcc2616 d068fc627				
Warnings:							
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## New Applications Under 35 U.S.C. 111

If a new application is being filed and the application includes the necessary components for a filing date (see 37 CFR 1.53(b)-(d) and MPEP 506), a Filing Receipt (37 CFR 1.54) will be issued in due course and the date shown on this Acknowledgement Receipt will establish the filing date of the application.

## National Stage of an International Application under 35 U.S.C. 371

If a timely submission to enter the national stage of an international application is compliant with the conditions of 35 U.S.C. 371 and other applicable requirements a Form PCT/DO/EO/903 indicating acceptance of the application as a national stage submission under 35 U.S.C. 371 will be issued in addition to the Filing Receipt, in due course.

## New International Application Filed with the USPTO as a Receiving Office

If a new international application is being filed and the international application includes the necessary components for an international filing date (see PCT Article 11 and MPEP 1810), a Notification of the International Application Number and of the International Filing Date (Form PCT/RO/105) will be issued in due course, subject to prescriptions concerning national security, and the date shown on this Acknowledgement Receipt will establish the international filing date of the application.